NSN 5962-01-120-5241

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View Online at https://aerobasegroup.com/nsn/5962-01-120-5241

Body Length:

Between 0.755 inches and 0.785 inches

Body Width:

0.280 inches

Body Height:

Between 0.165 inches and 0.210 inches

Maximum Power Dissipation Rating:

400.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

5820-01-108-9658 20183

Features Provided:

Hermetically sealed and w/enable and w/open collector and programmable and programmed

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

6 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts output logic low and 5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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